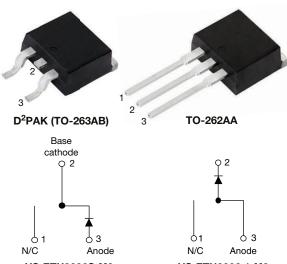
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VS-ETU3006S-M3, VS-ETU3006-1-M3

Vishay Semiconductors

Ultrafast Rectifier, 30 A FRED Pt[®]



VS-ETU3006S-M3

VS-ETU3006-1-M3

PRIMARY CHARACTERISTICS							
I _{F(AV)} 30 A							
V _R	600 V						
V _F at I _F	1.15 V						
t _{rr} (typ.)	30 ns						
T _J max.	175 °C						
Package	D ² PAK (TO-263AB), TO-262AA						
Circuit configuration	Single						

FEATURES

- Low forward voltage drop
- · Ultrafast recovery time
- 175 °C operating junction temperature
- · Low leakage current
- Designed and gualified according to JEDEC[®]-JESD 47
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

Ultralow V_F, soft-switching ultrafast rectifiers optimized for discontinuous (Critical) mode (DCM) power factor correction (PFC).

The minimized conduction loss, optimized stored charge and low recovery current minimized the switching losses and reduce over dissipation in the switching element and snubbers.

The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

APPLICATIONS

AC/DC SMPS 70 W to 400 W

e.g. laptop and printer AC adaptors, desktop PC, TV and monitor, games units, and DVD AC/DC power supplies.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Repetitive peak reverse voltage	V _{RRM}		600	V	
Average rectified forward current	I _{F(AV)}	T _C = 113 °C	30	٨	
Non-repetitive peak surge current	I _{FSM}	T _C = 25 °C	200	A	
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C	

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-					
	M	I _F = 30 A	-	1.4	2.0	V				
Forward voltage	V _F	I _F = 30 A, T _J = 150 °C	-	1.15	V 1.4 2.0 .15 1.35 .02 30 30 250 μA 20 - pF					
		$V_{\rm R} = V_{\rm R}$ rated	-	0.02	30					
Reverse leakage current	IR	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	30	250	μΑ				
Junction capacitance	CT	V _R = 600 V	-	20	-	pF				
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8.0	-	nH				

RoHS COMPLIANT HALOGEN FREE

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DYNAMIC RECOVERY	CHARACT	ERISTICS (T _J = 2	5 °C unless otherwi	se specifi	ed)		
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 50 \text{ A}$	õs, V _R = 30 V	-	30	45	
Reverse recovery time	t _{rr}	T _J = 25 °C		-	45	-	ns
		T _J = 125 °C		-	100	-	
Book receivers ourrent		T _J = 25 °C	I _F = 30 A dI _F /dt = 200 A/μs	-	5.6	-	А
Peak recovery current	I _{RRM}	T _J = 125 °C	$V_{\rm B} = 200 \text{ V}$	-	10	-	A
D	<u> </u>	T _J = 25 °C		-	127	-	nC
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	580	-	no

THERMAL - MECHANIC	CAL SPEC	IFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C
Thermal resistance, junction to case	R _{thJC}		-	0.95	1.4	°C/W
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	70	
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth, and greased	-	0.5	-	
Weight			-	2.0	-	g
Weight			-	0.07	-	oz.
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style D ² PAK (TO-263AB)	ETU3006S			
		Case style TO-262		ETU3	006-1	

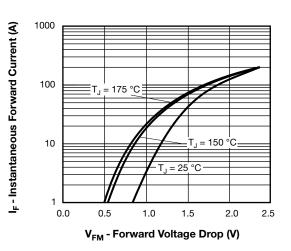


Fig. 1 - Typical Forward Voltage Drop Characteristics

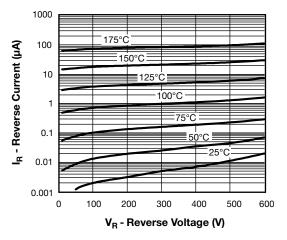


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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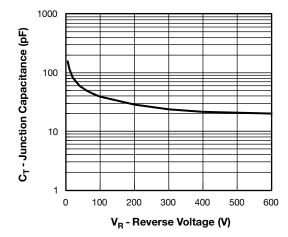


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

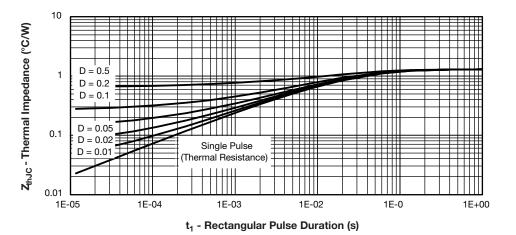


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics

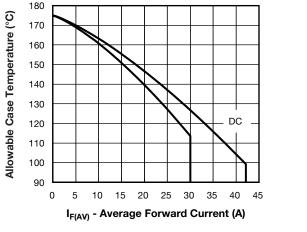


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

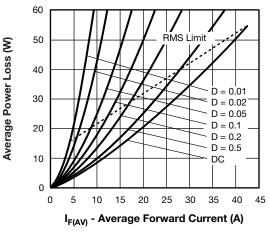


Fig. 6 - Forward Power Loss Characteristics

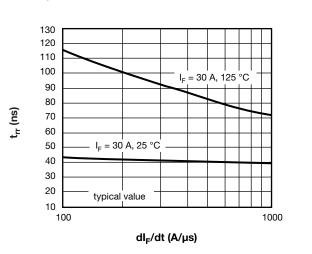
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Fig. 7 - Typical Reverse Recovery vs. dl_F/dt

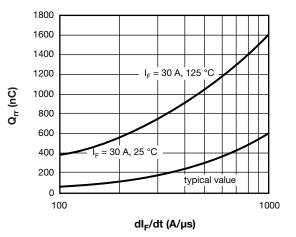


Fig. 8 - Typical Stored Charge vs. dl_F/dt

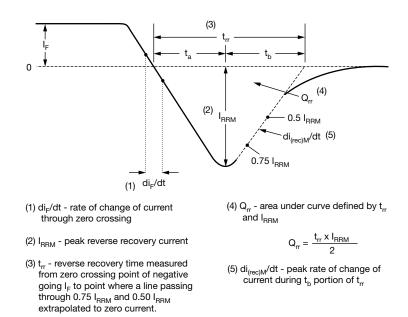


Fig. 9 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE

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SHAY

Device code	VS-	E	т	U	30	06	S	TRL	-M3	
	1	2	3	4	5	6	7	8	9	
	1 -	· Visl	nay Sem	niconduc	ctors pro	oduct				
	2 -		uit conf	iguratior	۱					
	3 -		TO-220							
	4 -	• U =	ultrafas	t recove	ery time					
	5 -	· Cur	rent coc	le (30 =	30 A)					
	6 -	· Vol	tage coo	le (06 =	600 V)					
	7 -	• S	= D ² PA	K (TO-2	63AB)					
	-	• -1	= TO-2	62AA						
	8 -	• No	one = tu	be (50 p	oieces)					
	-	• TF	RL = tap	e and re	el (left o	oriented	l, for D ²	PAK (T	O-263A	B) package
	-	• TF	RR = tap	e and re	eel (righ	t oriente	ed, for [D ² PAK	(TO-263	3AB) packag
	9 -	-M3	s = halog	gen-free	, RoHS-	complia	ant and	termina	ations le	ad (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION				
VS-ETU3006S-M3	50	Antistatic plastic tubes				
VS-ETU3006STRR-M3	800	13" diameter plastic tape and reel				
VS-ETU3006STRL-M3	800	13" diameter plastic tape and reel				
VS-ETU3006-1-M3	50	Antistatic plastic tubes				

LINKS TO RELATED DOCUMENTS							
Dimensions	D ² PAK (TO-263AB)	www.vishay.com/doc?96164					
Dimensions	TO-262AA	www.vishay.com/doc?96165					
Part marking information	D ² PAK (TO-263AB)	www.vishay.com/doc?95444					
Fart marking mornation	TO-262AA	www.vishay.com/doc?95443					
Packaging information	D ² PAK (TO-263AB)	www.vishay.com/doc?96424					
SPICE model		www.vishay.com/doc?96775					

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D²PAK

DIMENSIONS in millimeters and inches



ota	ted	90	°C
<u>S</u>	cale	<u>ə:</u> 8	:1

SYMBOL	MILLIM	MILLIMETERS		INCHES		
STMBOL	MIN.	MAX.	MIN. MAX.		NOTES	
A	4.06	4.83	0.160	0.190		
A1	0.00	0.254	0.000	0.010		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
с	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	

SYMBOL	MILLIM	ETERS	INCHES		NOTES	
	STINDOL	MIN.	MAX.	MIN.	MAX.	NOTES
	D1	6.86	8.00	0.270	0.315	3
	E	9.65	10.67	0.380	0.420	2, 3
	E1	7.90	8.80	0.311	0.346	3
	е	2.54	2.54 BSC		0.100 BSC	
	Н	14.61	15.88	0.575	0.625	
	L	1.78	2.79	0.070	0.110	
	L1	-	1.65	-	0.066	3
	L2	1.27	1.78	0.050	0.070	
	L3	0.25	BSC	0.010	BSC	
	L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Datum A and B to be determined at datum plane H

(6) Controlling dimension: inches

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

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Document Number: 96164

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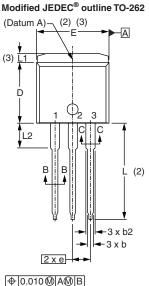
Outline Dimensions

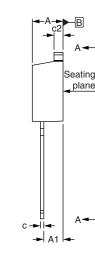


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TO-262AA

DIMENSIONS in millimeters and inches





F D1 (3) (3) Section A - A Base (4) Plating b1. b3 metal ≰ c1 (4) -(b, b2)-Section B - B and C - C Scale: None





Diodes 1. - Anode (two die)/open (one die) 2., 4. - Cathode 3. - Anode

Lead assignments

CVMPOI	MILLIN	IETERS	INC	HES	NOTES
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	BSC	0.100) BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

 ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the second dimensioner of the second dimensis and the second dimensioner of the second dimensioner of the the outmost extremes of the plastic body (3)

Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only (5)

Controlling dimension: inches

(6) Outline conform to JEDEC® TO-262 except A1 (max.), b (min., max.), b1 (min.), b2 (max.), c (min.), c1(min.), c2 (max.), D (min.), E (max.), L1 (max.), L2 (min., max.)

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